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SEVENTH SEMESTER B.TECH. (ENGINEERING) DEGREE EXAMINATION, DECEMBER 2006

EC 2K 702—MICROWAVE DEVICES AND COMMUNICATION

Time: Three Hours

Maximum 100 Marks

Answer all questions.

- 1. (a) Draw a neat sketch of E-plane Tee. Explain its characteristics. Derive its S-matrix.
 - (b) Explain the characteristics of circular cavity resonators.
 - (c) What type of tuning is employed in multicavity Klystron amplifier? Why? Explain.
 - (d) List and explain the types of magnetrons.
 - (e) State and explain Gunn effect. Also explain the high-field domain formation.
 - (f) Differentiate Tunnel diode from Zener diode.
 - (g) Explain the basic principles of microwave links with a neat sketch.
 - (h) What is a transponder? Explain its principle in detail.

 $(8 \times 5 = 40 \text{ marks})$

2. (a) Draw a neat sketch of reflex Klystron oscillator and explain its principle of operation. Describe its velocity and current modulations. Derive equations.

Or

- (b) Draw a neat cross-sectional diagram of circular magnetron. Explain its principle of oscillation and formation of "spokes".
- 3. (a) Explain the principle of 2 hole directional coupler, with a neat sketch. Explain its types. Derive S-matrix for an ideal 2 hole directional coupler.

Or

- (b) Derive TE and TM field equations of rectangular waveguide.
- 4. (a) State and explain Gunn effect. Explain its construction and fabrication in detail. Derive the condition for its negative resistance.

Or

- (b) Explain the principles of following diodes:—
 - (i) Inp diode.

(7 marks)

(ii) BARITT diode.

(8 marks)

5. (a) Explain the functioning of microwave transmitter and receiver with neat block diagrams.

Or

(b) (i) Derive an expression for pathless.

(7 marks)

(ii) Give a note on "Digital Modulation Schemes".

(8 marks)

 $[4 \times 15 = 60 \text{ marks}]$